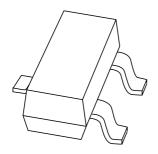
DISCRETE SEMICONDUCTORS

DATA SHEET



PMBT2222; PMBT2222A NPN switching transistors

Product specification Supersedes data of 1999 Apr 27 2004 Jan 22





Philips Semiconductors

NPN switching transistors

PMBT2222; PMBT2222A

FEATURES

- High current (max. 600 mA)
- Low voltage (max. 40 V).

APPLICATIONS

• Switching and linear amplification.

DESCRIPTION

NPN switching transistor in a SOT23 plastic package. PNP complements: PMBT2907 and PMBT2907A.

MARKING

| TYPE NUMBER | MARKING CODE(1) |
|-------------|-----------------|
| PMBT2222 | *1B |
| PMBT2222A | *1P |

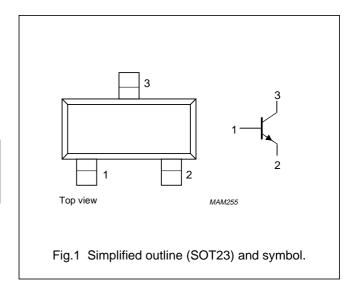
Note

1. * = p: Made in Hong Kong.

* = t : Made in Malaysia. * = W : Made in China.

ORDERING INFORMATION

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | base |
| 2 | emitter |
| 3 | collector |



| TYPE | PACKAGE | | | | |
|-----------|---------------------|--|--|--|--|
| NUMBER | NAME DESCRIPTION VE | | | | |
| PMBT2222 | _ | plastic surface mounted package; 3 leads | | | |
| PMBT2222A | | 3,7 | | | |

PINNING

NPN switching transistors

PMBT2222; PMBT2222A

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------|----------------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | | | |
| | PMBT2222 | | _ | 60 | V |
| | PMBT2222A | | _ | 75 | V |
| V _{CEO} | collector-emitter voltage | open base | | | |
| | PMBT2222 | | _ | 30 | V |
| | PMBT2222A | | _ | 40 | V |
| V _{EBO} | emitter-base voltage | open collector | | | |
| | PMBT2222 | | _ | 5 | V |
| | PMBT2222A | | _ | 6 | V |
| I _C | collector current (DC) | | _ | 600 | mA |
| I _{CM} | peak collector current | | _ | 800 | mA |
| I _{BM} | peak base current | | _ | 200 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C; note 1 | _ | 250 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |

Note

1. Transistor mounted on an FR4 printed-circuit board.

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------------|---|------------|-------|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | note 1 | 500 | K/W |

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 $T_i = 25$ °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|---------------------------|---|------|------|------|
| I _{CBO} | collector cut-off current | | | | |
| | PMBT2222 | I _E = 0; V _{CB} = 50 V | _ | 10 | nA |
| | | $I_E = 0$; $V_{CB} = 50 \text{ V}$ $I_E = 0$; $V_{CB} = 50 \text{ V}$; $T_j = 125 \text{ °C}$ | _ | 10 | μΑ |
| | collector cut-off current | | | | |
| | PMBT2222A | I _E = 0; V _{CB} = 60 V | _ | 10 | nA |
| | | $I_E = 0$; $V_{CB} = 60 \text{ V}$ $I_E = 0$; $V_{CB} = 60 \text{ V}$; $T_j = 125 \text{ °C}$ | _ | 10 | μΑ |
| I _{EBO} | emitter cut-off current | I _C = 0; V _{EB} = 5 V | | | |
| | PMBT2222A | | _ | 10 | nA |

NPN switching transistors

PMBT2222; PMBT2222A

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|--------------------|--------------------------------------|---|------|------|------|
| h _{FE} | DC current gain | I _C = 0.1 mA; V _{CE} = 10 V | 35 | 1- | |
| | | I _C = 1 mA; V _{CE} = 10 V | 50 | - | |
| | | I _C = 10 mA; V _{CE} = 10 V | 75 | Ī- | |
| | | $I_C = 10 \text{ mA}; V_{CE} = 10 \text{ V};$ $T_{amb} = -55 \text{ °C}$ | 35 | - | |
| | | I _C = 150 mA; V _{CE} = 10 V | 100 | 300 | |
| | | I _C = 150 mA; V _{CE} = 1 V | 50 | - | |
| | DC current gain | I _C = 500 mA; V _{CE} = 10 V | | | |
| | PMBT2222 | | 30 | _ | |
| | PMBT2222A | | 40 | _ | |
| V _{CEsat} | collector-emitter saturation voltage | I _C = 150 mA; I _B = 15 mA; note 1 | | | |
| | PMBT2222 | | _ | 400 | mV |
| | PMBT2222A | | _ | 300 | mV |
| | collector-emitter saturation voltage | $I_C = 500 \text{ mA}$; $I_B = 50 \text{ mA}$; note 1 | | | |
| | PMBT2222 | | _ | 1.6 | V |
| | PMBT2222A | | _ | 1 | V |
| V _{BEsat} | base-emitter saturation voltage | I _C = 150 mA; I _B = 15 mA; note 1 | | | |
| • DESat | PMBT2222 | | _ | 1.3 | V |
| | PMBT2222A | | 0.6 | 1.2 | V |
| | base-emitter saturation voltage | $I_C = 500 \text{ mA}$; $I_B = 50 \text{ mA}$; note 1 | | | |
| | PMBT2222 | , , , , , , | _ | 2.6 | V |
| | PMBT2222A | | _ | 2 | V |
| C _c | collector capacitance | I _E = I _e = 0; V _{CB} = 10 V; f = 1 MHz | _ | 8 | pF |
| C _e | emitter capacitance | $I_C = I_c = 0$; $V_{EB} = 500 \text{ mV}$; $f = 1 \text{ MHz}$ | | | ' |
| C | PMBT2222 | , | _ | 30 | pF |
| | PMBT2222A | | _ | 25 | pF |
| f _T | transition frequency | $I_C = 20 \text{ mA}; V_{CE} = 20 \text{ V}; f = 100 \text{ MHz}$ | | | ' |
| 1 | PMBT2222 | G , GE , | 250 | _ | MHz |
| | PMBT2222A | | 300 | _ | MHz |
| F | noise figure | I_C = 100 μA; V_{CE} = 5 V; R_S = 1 kΩ; f = 1 kHz | _ | 4 | dB |
| Switching ti | mes (between 10% and 90% levels); | | 1 | 1 | 1 |
| t _{on} | turn-on time | I _{Con} = 150 mA; I _{Bon} = 15 mA; | _ | 35 | ns |
| t _d | delay time | I _{Boff} = -15 mA | _ | 15 | ns |
| t _r | rise time | 1 | _ | 20 | ns |
| t _{off} | turn-off time | 1 | _ | 250 | ns |
| t _s | storage time | 1 | _ | 200 | ns |
| t _f | fall time | 1 | _ | 60 | ns |

Note

1. Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

NPN switching transistors

PMBT2222; PMBT2222A

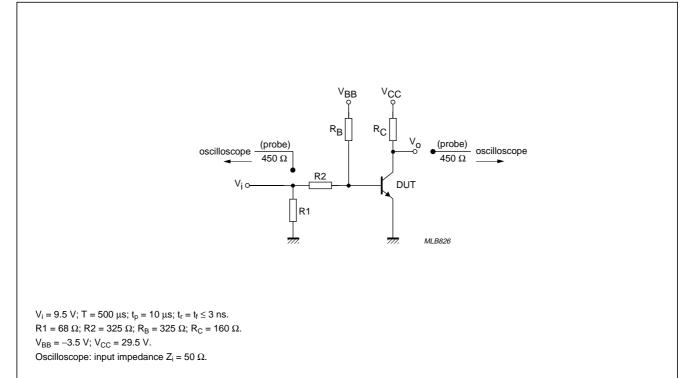


Fig.2 Test circuit for switching times.

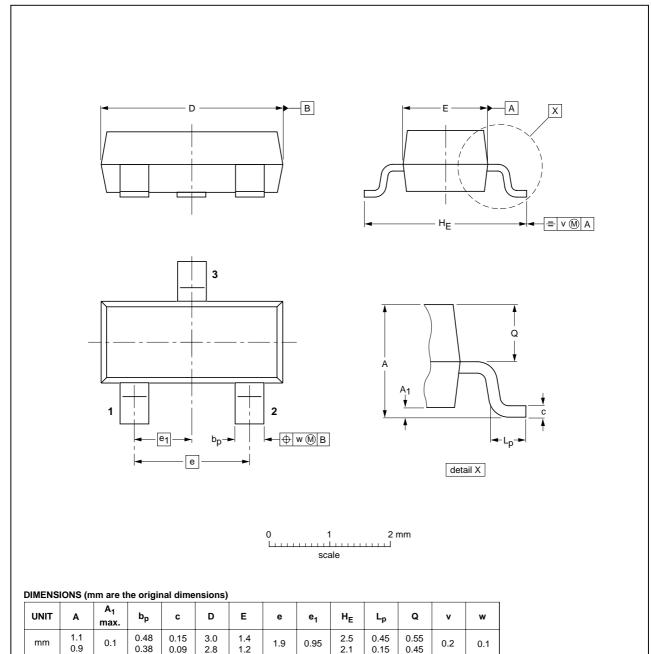
NPN switching transistors

PMBT2222; PMBT2222A

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



| OUTLINE | REFERENCES | | | EUROPEAN | ISSUE DATE | |
|---------|------------|----------|------|----------|--------------------|-----------------------------------|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION ISSUE L | |
| SOT23 | | TO-236AB | | | | -97-02-28- 99-09-13 |

NPN switching transistors

PMBT2222; PMBT2222A

DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS ⁽¹⁾ | PRODUCT STATUS(2)(3) | DEFINITION |
|-------|-------------------------------------|-------------------------|--|
| I | Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
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